PCN Number:		2023	30906001.1 <mark>A</mark>			PC	N Da	Date: September 6, 2023			
Title:	Qualification	of RFA	AB W	B Wafer Fab site using qualified Process Technology, Die Rev					hnology, Die Revision		
Tide.	and additiona	l Asse	e mbl	y site/BOM option	s for sele	ect d	levice	es			
Customer	Contact:		Cha	ange Management	team	De	pt:		Quality Services		
Proposed 1 st Ship Date:			Dec 6, 2023 Sample requests accepted until:			Oct 6, 2023*					
*Sample r	equests rece	ived	a fte	r October 6, 202	3 will n	ot b	e su	ppor	ted.		
Change Type:											
	ly Site		☑ Design					Wat	Wafer Bump Material		
⊠ Assemb	ly Process		☐ Data Sheet					Wafer Bump Process			
	ly Materials		Part number change			X	Wafer Fab Site				
■ Mechanical Specification		on	☐ Test Site			\boxtimes	Wat	Wafer Fab Materials			
□ Packing/Shipping/Labeling		☐ Test Process			\boxtimes	Wafer Fab Process					
	PCN Details										

Description of Change:

Revision A is to provide additional information highlighted below that was not included in the original PCN notification. NOTE: There are no samples offered as a result of this revision.

Texas Instruments is pleased to announce the addition of RFAB using the LBC7 qualified process technology and additional Assembly sites (PHI & CDAT) for the devices listed below in the product affected section.

С	urrent Fab Site	9	Additional Fab Site			
Current Fab Site			Additional Fab Site	Process	Wafer Diameter	
GFAB6	VIP1P	150 mm				
GFAB8	VIP1P	200 mm	RFAB	LBC7	300 mm	
DL-LIN	VIP1P	200 mm	N AD	LDC/		
SFAB	JI1	150 mm				

The die was also changed as a result of the process change.

For more information on the performance of the LBC7 die (new chip) and any differences with the V1P1P/JI1 die (legacy chip), please consult the datasheet revision listed below.

An example of that comparison is shown below:



LP2980-N

SNOS733Q - APRIL 2000 - REVISED NOVEMBER 2023

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (2)

		MIN	MAX	UNIT
V	Continuous input voltage range (for legacy chip)	-0.3	16	V
V _{IN}	Continuous input voltage range(for new chip)	-0.3	18	V
	Output voltage range (for legacy chip)	-0.3	9	V
V _{OUT}	Output voltage range(for new chip)	w chip) —0.3 (whichever is s	V _{IN} + 0.3 or 9 (whichever is smaller)	
v —	ON/OFF pin voltage range (for legacy chip)	-0.3	16	V
V _{ON/OFF}	ON/OFF pin voltage range (for new chip)	-0.3	18	V
Current	Maximum output	Internally	Internally limited	
Tomporatura	Operating junction, T _J	-55	150	°C
Temperature	Storage, T _{stg}	-65	150	°C

Construction differences are as follows:

Group 1 - (RFAB/Process migration + PHI & CDAT as additional Assembly sites):

	TFME	HNC	PHI	CDAT
Mount Compound	SID#A-03	SID#400154	8095733	4207123
Mold Compound	SID# R-17	SID#450228	4222198	4222198
Lead finish	Matte Sn	NiPdAu	NiPdAu	Matte Sn

Upon expiry of this PCN TI will combine lead free solutions in a single <u>standard part number</u>, for the devices in groups 1 & 2. For example; <u>LP2985-30DBVR</u> – can ship with both Matte Sn and NiPdAu/Ag.

Example:

- Customer order for 7500 units of LP2985-30DBVR with 2500 units SPQ (Standard Pack Quantity per Reel).
- TI can satisfy the above order in one of the following ways.
 - I. 3 Reels of NiPdAu finish.
 - II. 3 Reels of Matte Sn finish
 - III. 2 Reels of Matte Sn and 1 reel of NiPdAu finish.
 - IV. 2 Reels of NiPdAu and 1 reel of Matte Sn finish.

Qual details are provided in the Qual Data Section.

Reason for Change:

These changes are part of our multiyear plan to transition products from our 150-millimeter and 200-millimeter factories to newer, more efficient manufacturing processes and technologies, underscoring our commitment to product longevity and supply continuity.

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

None

Impact on Environmental Ratings:

Checked boxes indicate the status of environmental ratings following implementation of this change. If below boxes are checked, there are no changes to the associated environmental ratings.

RoHS REACH		Green Status	IEC 62474		
No Change	☑ No Change	No Change	No Change		

Changes to product identification resulting from this PCN:

Fab Site Information:

r ab oice zimormationi				
Chip Site	Chip Site Origin Code (20L)	Chip Site Country Code (21L)	Chip Site City	
GFAB6	GF6	GBR	Greenock	
GFAB8	GF8	GBR	Greenock	
DL-LIN	DLN	USA	Dallas	
SH-BIP-1	SHE	USA	Sherman	
RFAB	RFB	USA	Richardson	

Die Rev:

Current New

Die Rev [2P]	Die Rev [2P]
A. B. C	A

Assembly Site Information:

Assembly Site	Assembly Site Origin (22L)	Assembly Country Code (23L)	Assembly City
TFME	NFM	CHN	Economic Development Zone
HNC	CHS	CHN	Jiaxing City
PHI	PHI	PHL	Baguio City
CDAT	CDA	CHN	Chengdu

Sample product shipping label (not actual product label)



2DC: 2Q: MSL '2 /260C/1 YEAR SEAL DT MSL 1 /235C/UNLIM 03/29/04

OPT: ITEM:

DL: 5A (L)TO:1750



(1P) \$N74L\$07N\$R (Q) 2000 (D) 0336 (31T)LOT: 3959047MLA (4W) TKY(1T) 7523483812

(2P) REV: (V) 0099317 (20L) CSO: SHE (21L) CCO:USA (22L) ASO: MLA (23L) ACO: MYS

Product Affected:

Group 1 Device List (RFAB/Process migration + PHI & CDAT as additional Assembly sites):

LP2985-18DBVR	LP2985-33DBVT	LP2985A-25DBVR	LP2985A-33DBVT
LP2985-30DBVR	LP2985-50DBVR	LP2985A-33DBVR	LP2985A-33DBVTG4
LP2985-33DBVR	LP2985-50DBVT	LP2985A-33DBVRG4	LP2985A-50DBVR
LP2985-33DBVRG4	LP2985A-18DBVR		

Group 2 Device List (RFAB/Process migration only):

LP2980AIM5-2.5/NOPB	LP2980IM5X-ADJ/NOPB	LP2985AIM5X-1.8/NOPB	LP2985IM5-3.5/NOPB
LP2980AIM5-3.0/NOPB	LP2985-25DBVR	LP2985AIM5X-2.5/NOPB	LP2985IM5-3.6/NOPB
LP2980AIM5-3.3/NOPB	LP2985-28DBVR	LP2985AIM5X-2.8/NOPB	LP2985IM5-3.8/NOPB
LP2980AIM5-5.0/NOPB	LP2985A-30DBVR	LP2985AIM5X-3.0/NOPB	LP2985IM5-4.0/NOPB
LP2980AIM5X-3.0/NOPB	LP2985A-50DBVT	LP2985AIM5X-3.3/NOPB	LP2985IM5-4.5/NOPB
LP2980AIM5X-3.3/NOPB	LP2985AIM5-1.8/NOPB	LP2985AIM5X-3.6/NOPB	LP2985IM5-5.0/NOPB
LP2980AIM5X-5.0/NOPB	LP2985AIM5-2.5/NOPB	LP2985AIM5X-4.0/NOPB	LP2985IM5X-1.8/NOPB
LP2980IM5-3.0/NOPB	LP2985AIM5-3.0/NOPB	LP2985AIM5X-4.5/NOPB	LP2985IM5X-2.5/NOPB
LP2980IM5-3.3/NOPB	LP2985AIM5-3.3/NOPB	LP2985AIM5X-5.0/NOPB	LP2985IM5X-2.8/NOPB
LP2980IM5-5.0/NOPB	LP2985AIM5-3.6/NOPB	LP2985IM5-1.8/NOPB	LP2985IM5X-3.0/NOPB
LP2980IM5-ADJ/NOPB	LP2985AIM5-3.8/NOPB	LP2985IM5-2.5/NOPB	LP2985IM5X-3.3/NOPB
LP2980IM5X-2.5/NOPB	LP2985AIM5-4.0/NOPB	LP2985IM5-2.8/NOPB	LP2985IM5X-4.0/NOPB
LP2980IM5X-3.0/NOPB	LP2985AIM5-4.5/NOPB	LP2985IM5-3.0/NOPB	LP2985IM5X-4.5/NOPB
LP2980IM5X-3.3/NOPB	LP2985AIM5-5.0/NOPB	LP2985IM5-3.3/NOPB	LP2985IM5X-5.0/NOPB
LP2980IM5X-5.0/NOPB			

For alternate parts with similar or improved performance, please visit the product page on II.com

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: LP2980IM5- ADJ/NOM3	QBS Process Reference: IPS2543QRIETQ1	QBS Process Reference: TLV76790QWDRBRQ1	QBS Product Reference: LP2985A- 50DBVRM3	QBS Package Reference: TPS3840PH30DBVRQ1
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	-	-	1/77/0	3/231/0
UHAST	A3	Autoclave	121C/15psig	96 Hours	-	-	-	-	3/231/0
UHAST	A3	Unbiased HAST	130C/85%RH	96 Hours	-	-	-	1/77/0	-
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	-	-	1/77/0	3/231/0
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	-	3/135/0
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	-	-	1/77/0	-
HTOL	B1	Life Test	125C	1000 Hours	-	3/231/0	1/77/0	-	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/2400/0	-	-	-

Туре	#	Test Name	Condition	Duration	Qual Device: <u>LP2980IM5-</u> <u>ADJ/NOM3</u>	QBS Process Reference: TPS2543QRTETQ1	QBS Process Reference: TLV76790QWDRBRQ1	QBS Product Reference: LP2985A- 50DBVRM3	QBS Package Reference: <u>TPS3840PH30DBVRQ1</u>
SD	C3	PB Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-		-	1/15/0
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-	-	-	1/15/0
PD	C4	Physical Dimensions	Cpk>1.67	-	-	-	-	-	3/30/0
ESD	E2	ESD CDM	-	250 Volts	1/3/0	-	-	-	-
ESD	E2	ESD HBM	-	1000 Volts	1/3/0	-	-	-	-
LU	E4	Latch-Up	Per JESD78	-	1/3/0	-	-	-	-
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/PASS	-	-	-	-

- Qual Device LP2980IM5-ADJ/NOM3 is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-NPD-2304-007

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: <u>LP2985-</u> <u>50DBVRM3</u>	QBS Product/Process Reference: <u>TPS2543QRTE</u>	QBS Product/Package Reference: <u>TLV70233DBVR</u>	QBS Product/Package Reference: <u>TPS2514DBVR</u>	QBS Product/Package Reference: <u>TPS2552DBVR</u>
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	3/231/0	-	-	3/231/0
ACLV	А3	Autoclave	121C/15psig	96 Hours	-	3/231/0	3/231/0	-	3/231/0
UHAST	А3	Unbiased HAST	130C/85%RH	96 Hours	-	-	-	-	
тс	A4	Temperature Cycle	-65C/150C	500 Cycles	-	3/231/0	3/231/0	3/231/0	3/231/0
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	-	-
HTSL	A6	High Temperature Storage Life	170C	420 Hours		3/135/0	3/231/0		3/231/0
HTOL	B1	Life Test	150C	408 Hours	-	3/231/0	-	-	-
ELFR	B2	Early Life Failure Rate	150C	24 Hours	-	3/2400/0	-	-	-
WBS	C1	Wire Bond Pull	-	-	-	-	3/228/0	3/228/0	3/228/0
WBP	C2	Wire Bond Shear	-	-	-	-	3/228/0	3/228/0	3/228/0
SD	С3	Solderability	-	-	-	-	3/66/0	-	
PD	C4	Physical Dimension	-	-	-	-	3/15/0	3/15/0	3/15/0
ESD	E2	ESD HBM	-	1000 Volts	1/3/0	1/3/0	-	-	-
ESD	E2	ESD HBM	-	2500 Volts	1/3/0	1/3/0	-	-	-
ESD	E3	ESD CDM	-	250 Volts	1/3/0	1/3/0	-	-	-
ESD	E3	ESD CDM	-	1500 Volts	1/3/0	1/3/0	-	-	-
LU	E4	Latch-Up	Per JESD78	-	1/6/0	1/6/0	-	-	-
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	1/30/0	3/90/0	-	-	-
MQ	-	MQ (Assembly)	Per Site Specification	-	1/30/0	-	-	-	-

- QBS: Qual By Similarity

- QBS: Qual By Similarity
 Qual Device LP2985-SODBVRM3 is qualified at LEVEL1-260C
 Concurrently qualifies the following product families:

 LP2985: LP2985-330BWR, LP2985-500BWR, LP2985-180BWR, LP2985-33DBVT, LP2985-50DBVT
 LP2985: 33DBVRM3, LP2985-50DBVRM3, LP2985-180BWRM3, LP2985-33DBVTM3, LP2985-50DBVTM3
 LP2985A-330BWR, LP2985A-50DBVR, LP2985A-30DBVT, LP2985A-50DBVT, LP2985A-33DBVRM3 and LP2985A-50DBVRM3
 LP2985A-182985A-33DBVR, LP2985A-50DBVR, LP2985A-33DBVT, LP2985A-33DBVT,
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV: 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and

Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free (SMT) and Green

TI Qualification ID: R-NPD-2202-124

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: LP2980AIM5X- 5.0/NO	QBS Process Reference: <u>TPS2543QRTETQ1</u>	QBS Package Reference: TLV9061IDBVR	QBS Process/Product Reference: TLV76790QWDRBRQ1	QBS Package/Process/Product Reference: <u>LP2985A-</u> <u>50DBVRM3</u>
HAST	A2	Biased HAST	130C/85%RH	96 Hours	-	-	3/231/0	-	1/77/0
UHAST	А3	Unbiased HAST	130C/85%RH	96 Hours	-	-	3/231/0	-	1/77/0
TC	A4	Temperature Cycle	-65C/150C	500 Cycles	-	-	3/231/0	-	1/77/0
HTSL	A6	High Temperature Storage Life	170C	420 Hours	-	-	3/231/0	-	1/77/0
HTOL	B1	Life Test	125C	1000 Hours	-	3/231/0	-	1/77/0	-
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/2400/0	-	-	-
WBS	C1	Ball Shear	76 balls, 3 units min	Wires	-	-	3/228/0	-	-
WBP	C2	Bond Pull	76 Wires, 3 units min	Wires	-	-	3/228/0	-	-

Туре	#	Test Name	Condition	Duration	Qual Device: LP2980AIM5X- 5.0/NO	QBS Process Reference: <u>TPS2543QRTETQ1</u>	QBS Package Reference: TLV9061IDBVR	QBS Process/Product Reference: TLV76790QWDRBRQ1	QBS Package/Process/Product Reference: <u>LP2985A-</u> 50DBVRM3
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes); PB- Free Solder;	-	-	-	3/66/0	-	
PD	C4	Physical Dimensions	(per mechanical drawing)	-	-	-	3/15/0	-	-
ESD	E2	ESD CDM	-	250 Volts	-	-	-	-	1/3/0
ESD	E2	ESD CDM	-	500 Volts	-	-	-	1/3/0	-
ESD	E2	ESD HBM	-	1000 Volts	-	-	-	-	1/3/0
ESD	E2	ESD HBM	-	2000 Volts	-	-	-	1/3/0	-
LU	E4	Latch-Up	Per JESD78	-	-	-	-	1/6/0	1/6/0
CHAR	E5	Electrical Characterization	Per Datasheet Parameters	-	-	-	-	-	1/PASS
CHAR	E5	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	-	-	-	3/PASS	-
FTY	E6	Final Test Yield	-	-	1/PASS	-	-	-	-

- QBS: Qual By Similarity
- Qual Device LP2980AIM5X-5.0/NO is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- $\bullet \ \ \, \text{The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours}$
- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

TI Qualification ID: R-CHG-2305-084

Data Displayed as: Number of lots / Total sample size / Total failed

Туре	#	Test Name	Condition	Duration	Qual Device: LP2985A50DBVRM3	QBS Reference: TPS2543QRTETQ1	QBS Reference: TLV76790QWDRBRQ1	QBS Reference: LP298550DBVRM3	QBS Reference: TPS3840PH30DBVRQ1
HAST	A2	Biased HAST	130C/85%RH	96 Hours	1/77/0	3/231/0	3/231/0	-	3/231/0
UHAST	А3	Autoclave	121C/15psig	96 Hours	-	-	-	-	3/231/0
UHAST	А3	Unbiased HAST	130C/85%RH	96 Hours	1/77/0	3/231/0	3/231/0	-	-
тс	Α4	Temperature Cycle	-65C/150C	500 Cycles	1/77/0	3/231/0	3/231/0	-	3/231/0
HTSL	A6	High Temperature Storage Life	150C	1000 Hours	-	-	-	-	3/135/0
HTSL	A6	High Temperature Storage Life	170C	420 Hours	1/77/0	-	-	-	-
HTSL	A6	High Temperature Storage Life	175C	500 Hours	-	3/135/0	3/231/0	-	-
HTOL	B1	Life Test	125C	1000 Hours	-	3/231/0	1/77/0	-	3/231/0
ELFR	B2	Early Life Failure Rate	125C	48 Hours	-	3/2400/0	-	-	-
SD	C3	PB Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	-	-	-	1/15/0
SD	C3	PB-Free Solderability	Precondition w.155C Dry Bake (4 hrs +/- 15 minutes)	-	-	1/15/0	-	-	1/15/0
PD	C4	Physical Dimensions	-	-	1/10/0	3/30/0	2/20/0	-	3/30/0
ESD	E2	ESD CDM	-	1500 Volts	1/3/0	1/3/0	1/3/0	-	-
ESD	E2	ESD HBM	-	4000 Volts	1/3/0	-	-	1/3/0	-
LU	E4	Latch-Up	Per JESD78	-	1/6/0	1/6/0	1/6/0	1/6/0	-
CHAR	E5	Electrical Characterization By Similarity	Per Datasheet Parameters	-	_(1)	3/90/0	3/90/0	1/30/0	3/90/0

- QBS: Qual By Similarity
- Qual Device LP2985A-50DBVRM3 is qualified at MSL1 260C
- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable
- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours
- The following are equivalent HTSL options based on an activation energy of 0.7eV: 150C/1k Hours, and 170C/420 Hours
- The following are equivalent Temp Cycle options per JESD47: -55C/125C/700 Cycles and -65C/150C/500 Cycles Quality and

 $Environmental\ data\ is\ available\ at\ TI's\ external\ Web\ site: \\ \underline{http://www.ti.com/}\ Green/Pb-free\ Status:$

Qualified Pb-Free(SMT) and Green

TI Qualification ID: R-NPD-2202-123

Notes:

(1) Electrical Characterization performed on LP2985A-18DBVRM3 and LP2985A-33DBVRM3

For questions regarding this notice, e-mails can be sent to the Change Management team or your local Field Sales Representative.

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